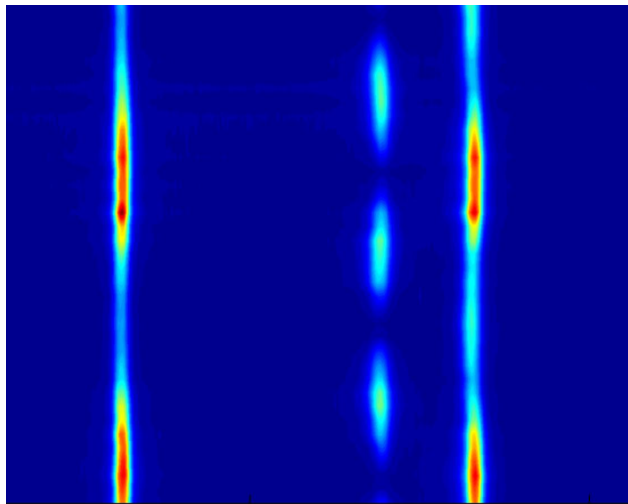




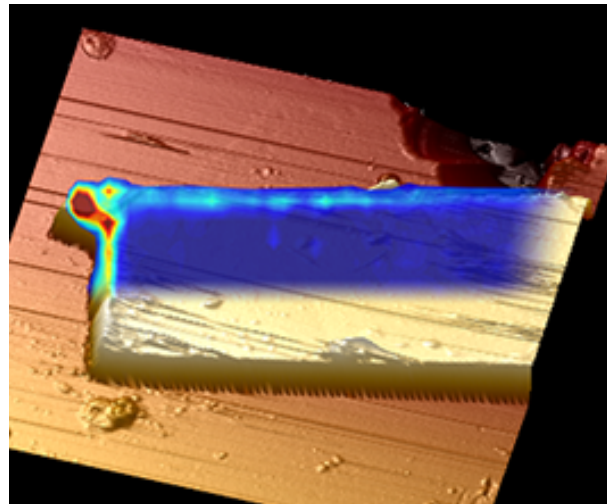
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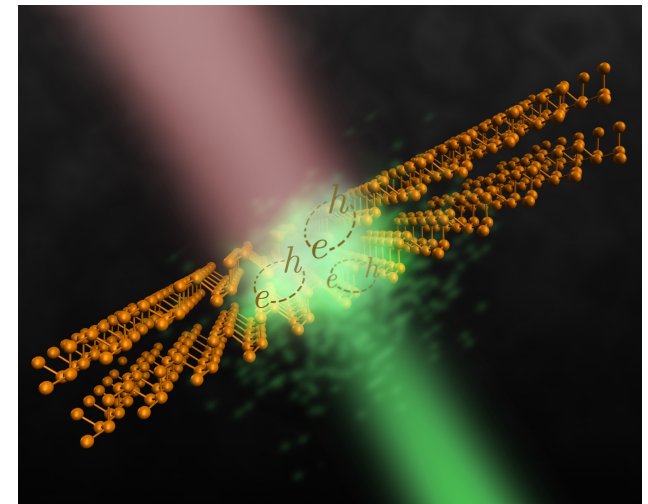
The Unusual Raman and Optical Properties of Black Phosphorus



ACS Nano 9, 4270 (2015)



Nature Commun. 7, 12191 (2016)



Adv. Mater. 28, 10693 (2016)

Christiano J. S. de Matos

MackGraphe - Mackenzie Presbyterian University, Brazil

cjsdematos@mackenzie.br • www.mackenzie.br/mackgraphe.html



Talk outline

- Black phosphorus (BP): an anisotropic layered semiconductor
- Raman response in BP
 - Unusual dependence on light polarization
 - Edge phonons
- Nonlinear optical response in BP
 - Third-harmonic generation
- Conclusions



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About MackGraphe

(Graphene and Nanomaterials Research Center)

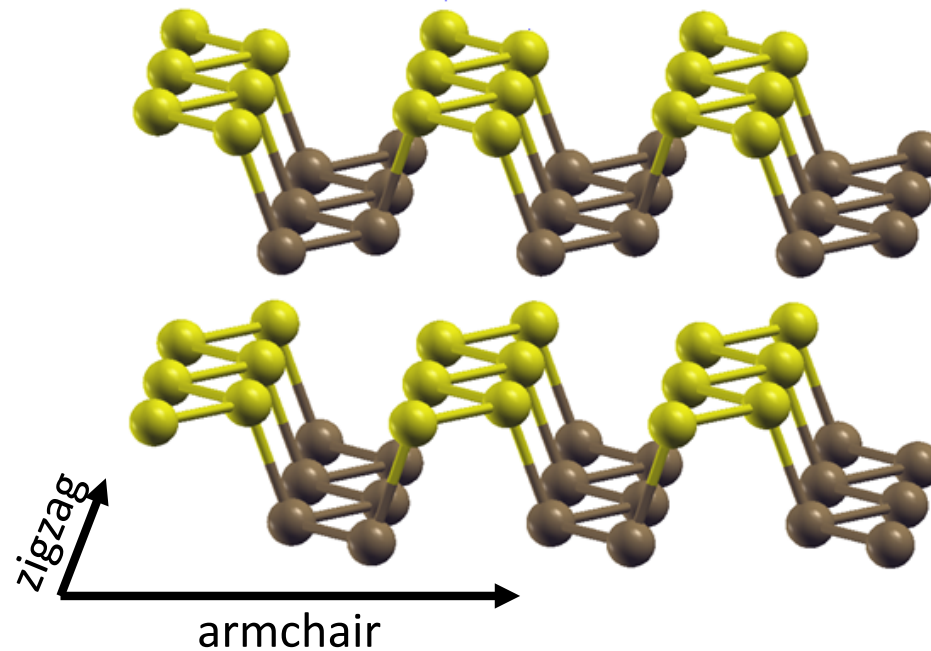


- Located at the Mackenzie Presbyterian University, São Paulo, Brazil
- Began its activities in 2013
- Headquarters building opened on 2 march 2016
- 3 areas of interest: Photonics, Energy, Composite Materials
- **Positions available!**

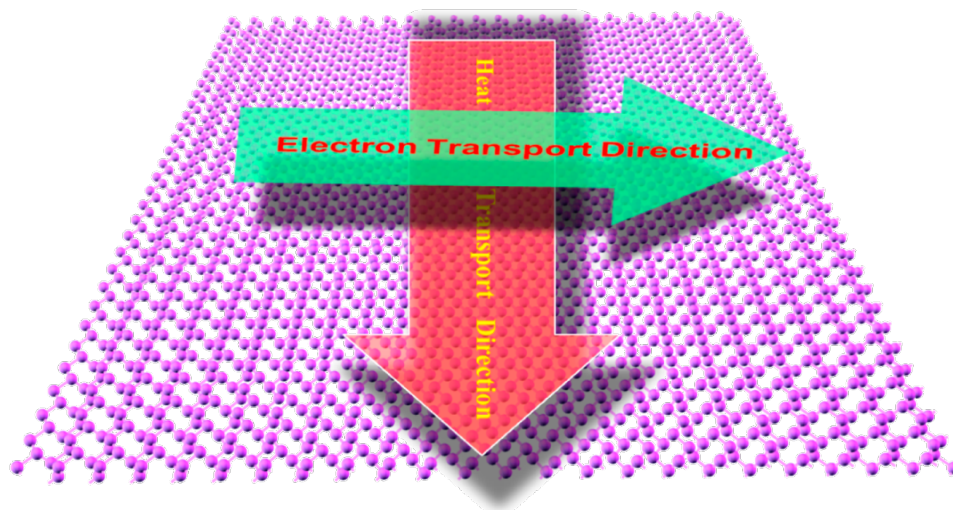


Black Phosphorus

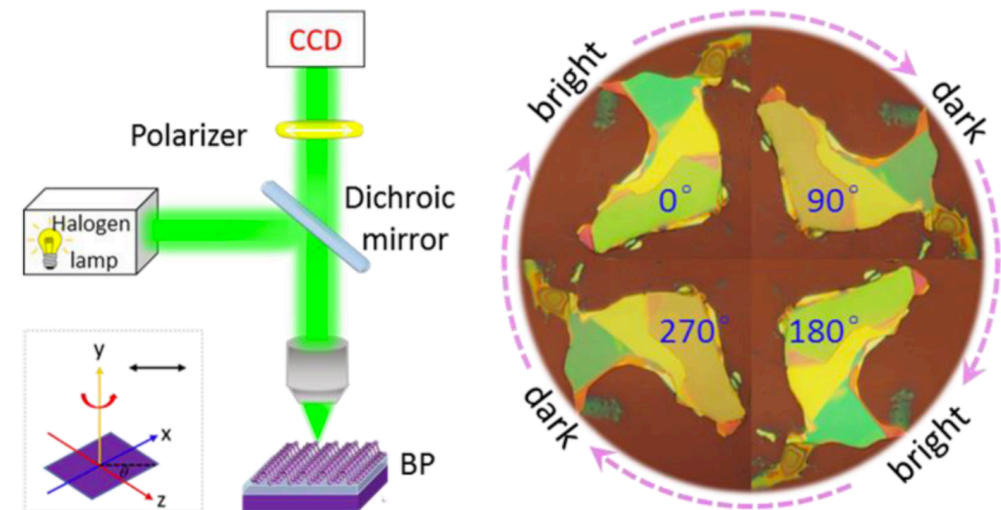
- Highly anisotropic puckered structure
 - orthorhombic, point group D_{2h} , centrosymmetric



Angle dependent heat & electronic conduction



Birefringence & linear dichroism

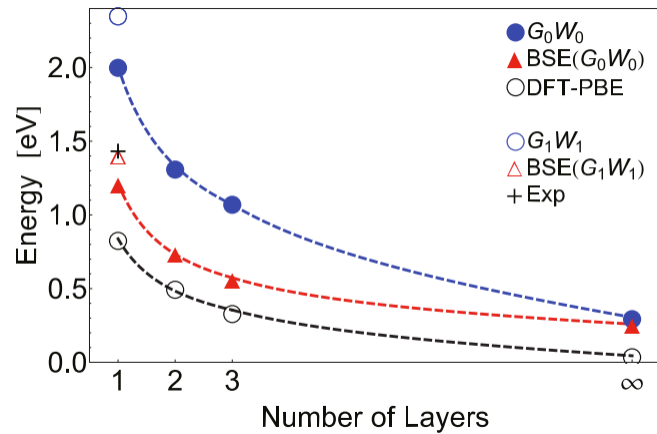




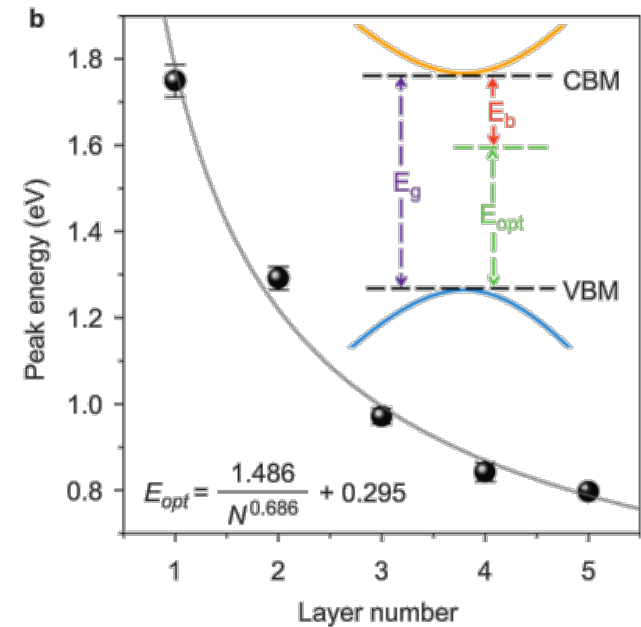
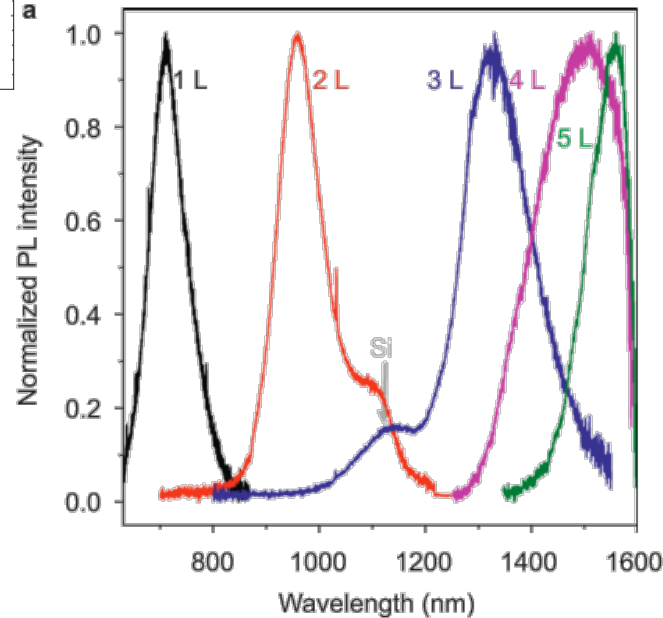
Black Phosphorus

- A direct bandgap semiconductor from bulk to the monolayer; gap increases with thickness reduction

Tran et al., Phys. Rev. B 89, 235319 (2014)



Highly bound (room temperature) excitons



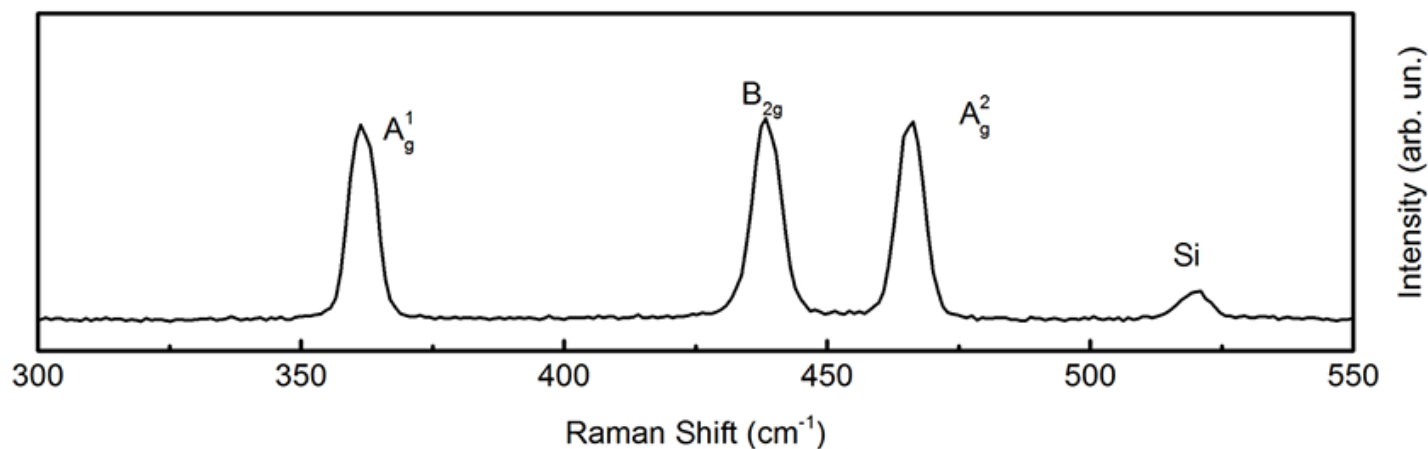


Motivation to this work

- Properties suggest important applications in
 - Electronics
 - Optoelectronics
 - Photonics
- Thorough characterization of the crystal is imperative
- **Here:**
 - Polarized Raman characterization and identification of complex Raman tensor elements
 - Changes in Raman mode symmetries at the crystal edges
 - Enhanced nonlinear optical frequency conversion in few-layer flakes



Raman spectroscopy in black phosphorus

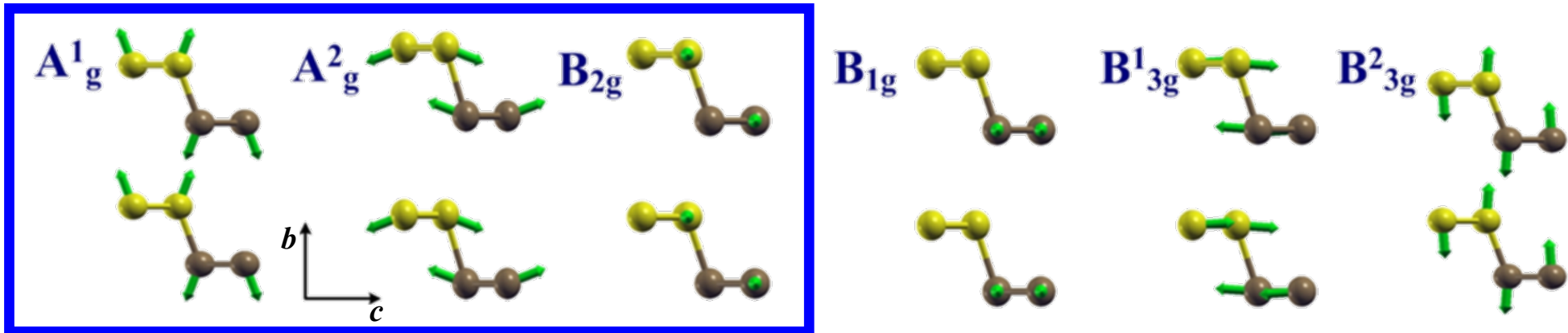


Soon: a review in Journal of Raman Spectroscopy



Raman modes in BP

- 6 Raman active modes

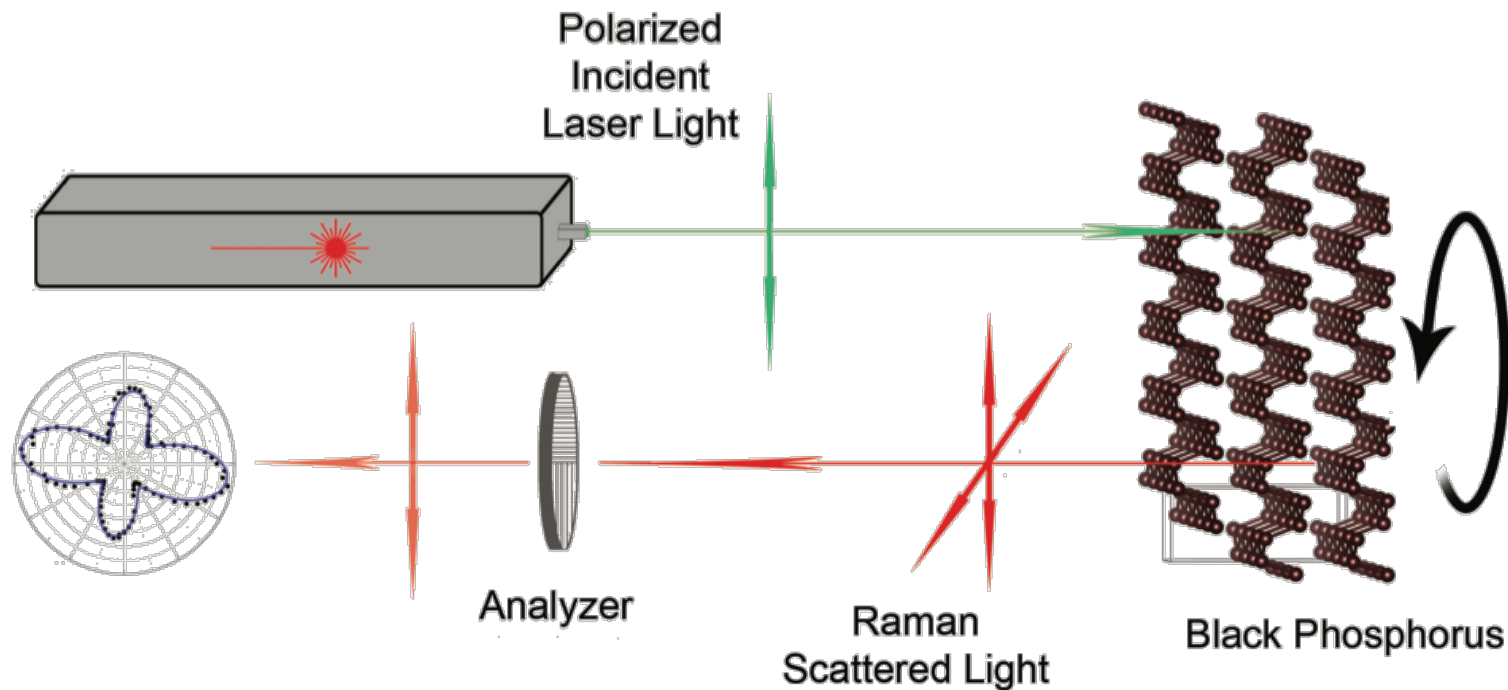


Light incident along y

Raman tensors obtained from the dielectric tensor:

$$R_{ij}^k = \frac{\partial \epsilon_{ij}}{\partial q^k} \quad S_k \propto |\hat{\mathbf{e}}_i \cdot R^k \cdot \hat{\mathbf{e}}_s|^2$$

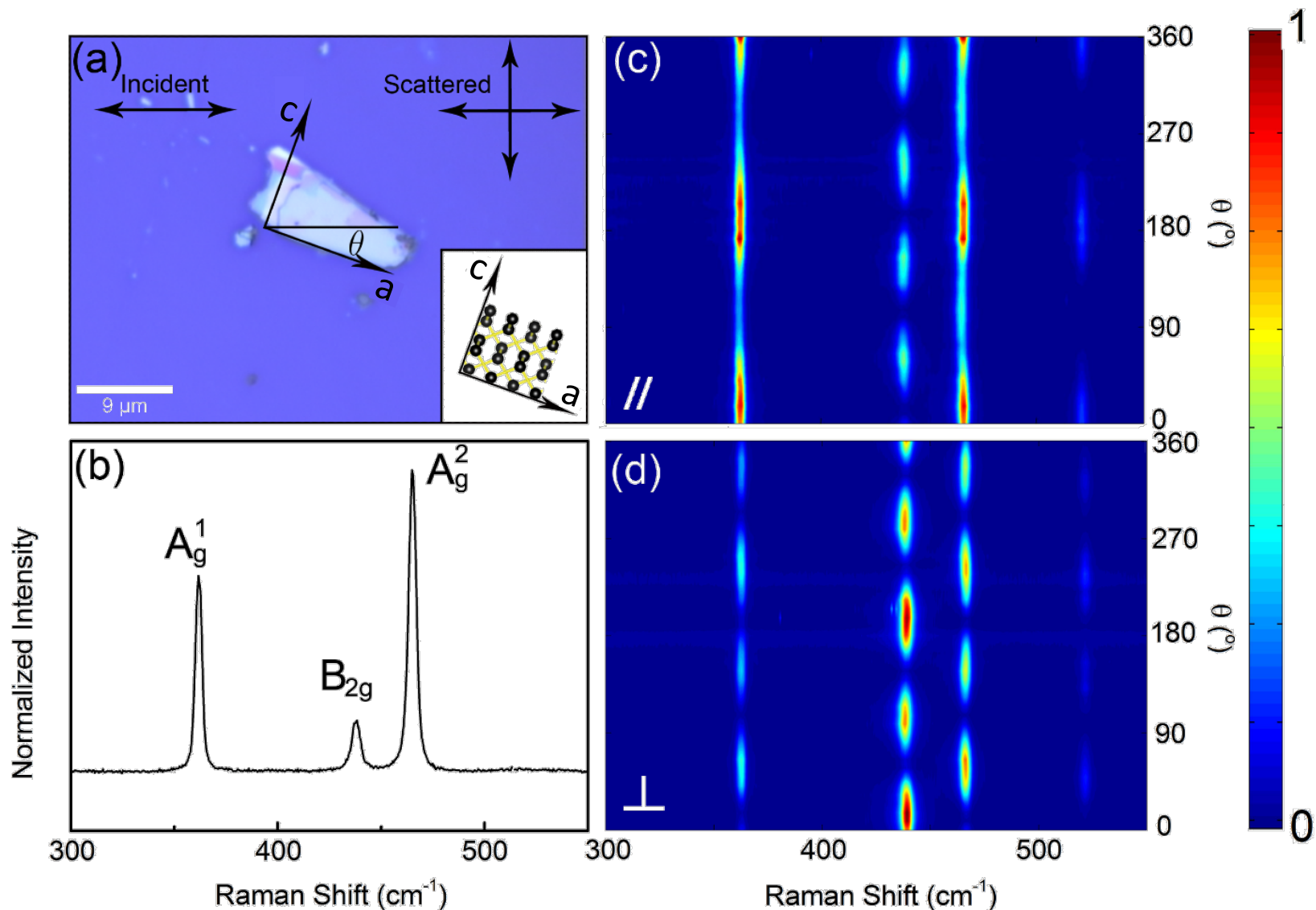
Mode	A_g	B_{1g}	B_{2g}	B_{3g}
Tensor	$\begin{pmatrix} a & 0 & 0 \\ 0 & b & 0 \\ 0 & 0 & c \end{pmatrix}$	$\begin{pmatrix} 0 & d & 0 \\ d & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix}$	$\begin{pmatrix} 0 & 0 & f \\ 0 & 0 & 0 \\ f & 0 & 0 \end{pmatrix}$	$\begin{pmatrix} 0 & 0 & 0 \\ 0 & 0 & g \\ 0 & g & 0 \end{pmatrix}$



- Parallel configuration: $\hat{e}_i \parallel \hat{e}_s$
- Orthogonal configuration: $\hat{e}_i \perp \hat{e}_s$



Polarized Raman spectroscopy: results

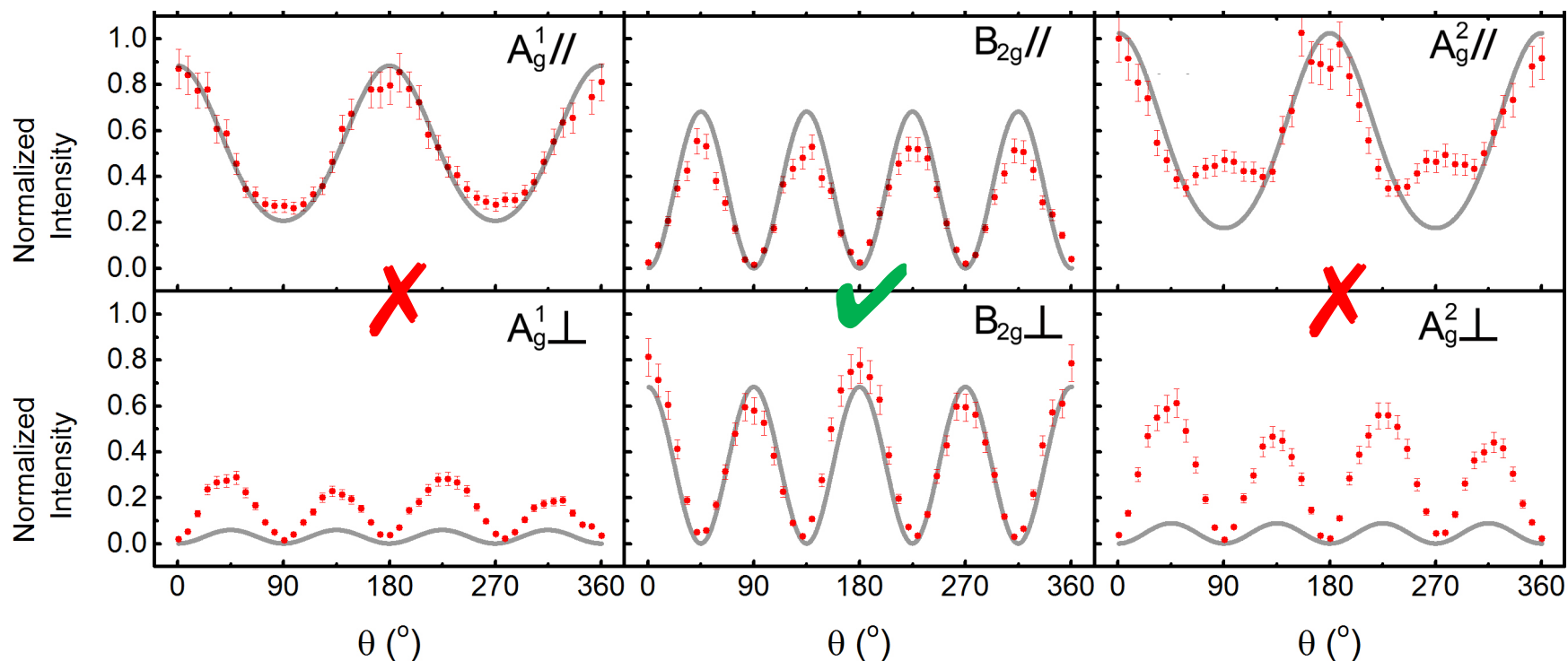




Polarized Raman spectroscopy: conventional analysis



Mode	A_g	B_{2g}		
Tensor	$\begin{pmatrix} a & 0 & 0 \\ 0 & b & 0 \\ 0 & 0 & c \end{pmatrix}$	$\begin{pmatrix} 0 & 0 & f \\ 0 & 0 & 0 \\ f & 0 & 0 \end{pmatrix}$	$S_{A_g}^{\parallel} = (a \cdot \cos^2\theta + c \cdot \sin^2\theta)^2$	$S_{B_{2g}}^{\parallel} = (2f \cdot \sin\theta \cos\theta)^2$
			$S_{A_g}^{\perp} = (a - c)^2 \sin^2\theta \cos^2\theta$	$S_{B_{2g}}^{\perp} = (f \cdot \cos 2\theta)^2$





Unusual angular dependence of the Raman response in BP



$$R_{ij}^k = \frac{\partial \epsilon_{ij}}{\partial q^k} = \frac{\partial \epsilon'_{ij}}{\partial q^k} + i \frac{\partial \epsilon''_{ij}}{\partial q^k}$$

$$a = |a|e^{i\phi_a}, \quad c = |c|e^{i\phi_c}, \quad f = |f|e^{i\phi_f}$$

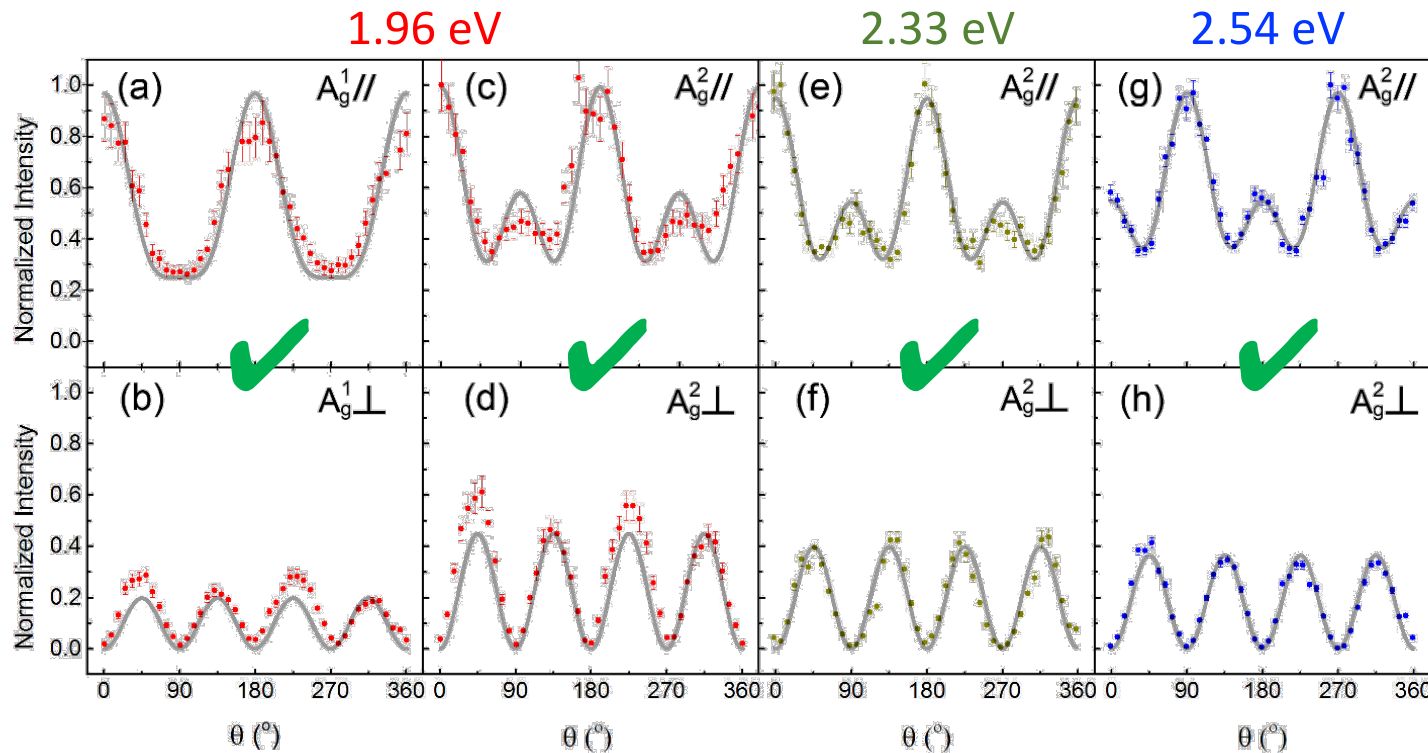
Dichroism: Complex values of the Raman tensors

$$S_{A_g}^{\parallel} = (|a|\cos^2\theta + |c|\cos\phi_{ac}\sin^2\theta)^2 + c^2\sin^4\theta\sin^2\phi_{ac}$$

$$S_{A_g}^{\perp} = [(|a| - |c|\cos\phi_{ac})^2 + |c|^2\sin^2\phi_{ac}]\sin^2\theta\cos^2\theta$$

$$S_{B_{2g}}^{\parallel} = (2|f|\sin\theta\cos\theta)^2$$

$$S_{B_{2g}}^{\perp} = (|f|\cos 2\theta)^2$$



H. B. Ribeiro et al., ACS Nano 9, 4270 (2015)



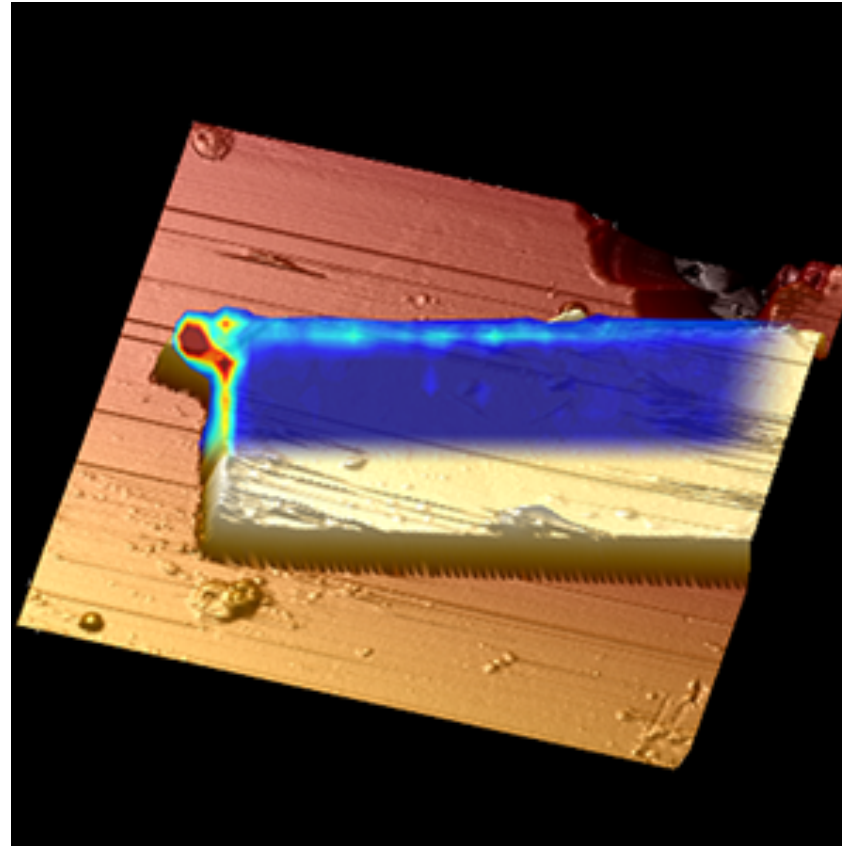
Unusual angular dependence of the Raman response in BP



- Later work showed need to account also for
 - Flake thickness [Kim et al., Nanoscale 7 , 18708 (2015)] [Ling et al., Nano Lett 16, 2260 (2016)]
- Same trend also observed in other layered materials
 - $\text{ReS}_2/\text{ReSe}_2$ [Lorchat et al., ACS Nano 10, 2752–2760 (2016)]
 - WTe_2 [Song et al., Scientific Reports 6, 29254 (2016)]



Edge phonons in BP



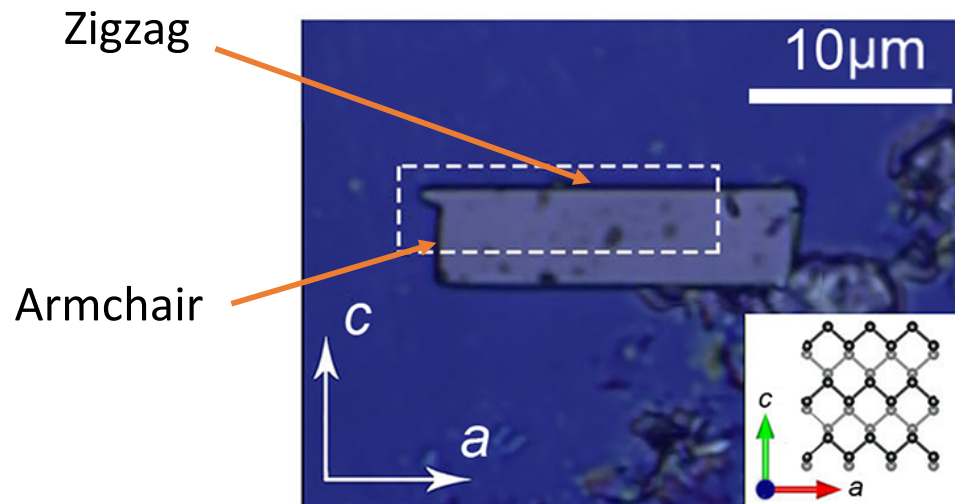
- Polarized Raman maps across BP flakes revealed anomalous mode appearance at the edges
- Mode appearance also depends on the edge type: zigzag or armchair



Edge phonons in BP: experiment



- Selected flakes exhibit well defined edge character



- Incident polarization X (\parallel to a) or Z (\parallel to c)
- Analysed polarization X or Z
- Analysed polarization configurations
 - Parallel: XX, ZZ
 - Orthogonal: XZ, ZX

Bulk phonons

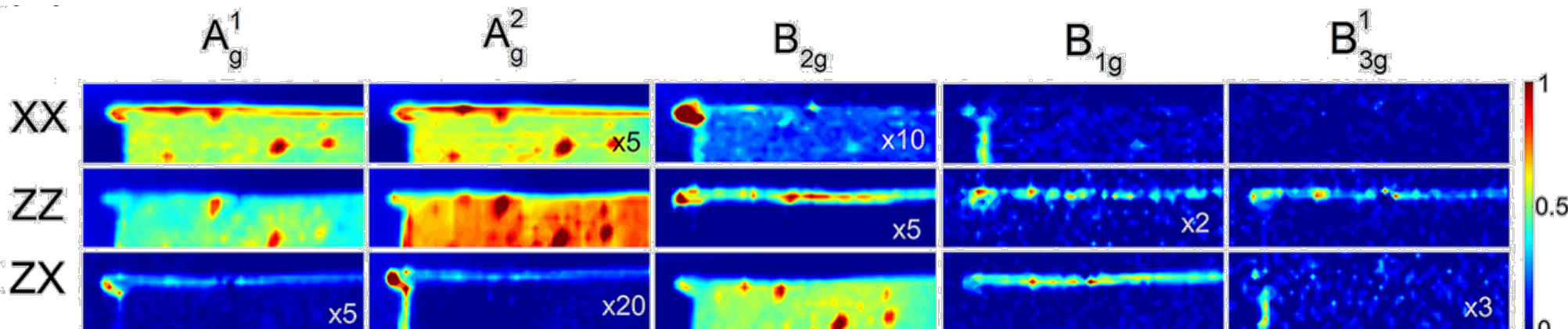
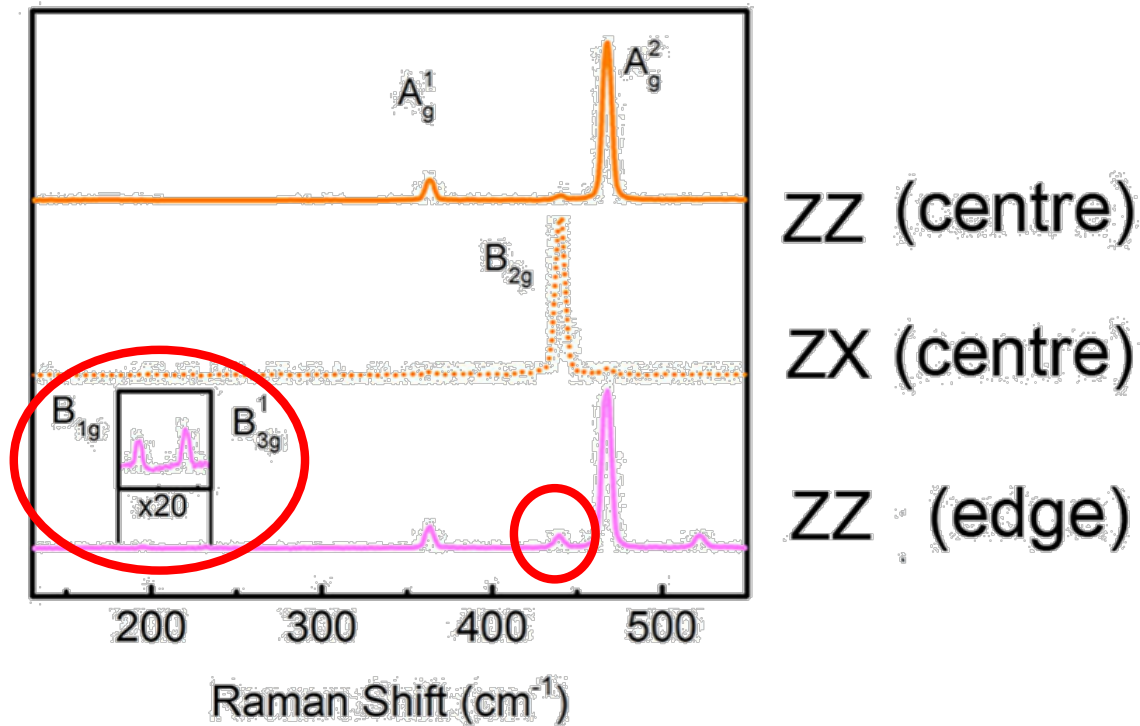
$A_g \Rightarrow$ (XX) and (ZZ)

$B_{2g} \Rightarrow$ (XZ) and (ZX)

B_{1g}, B_{3g} not visible



Edge phonons in BP: results

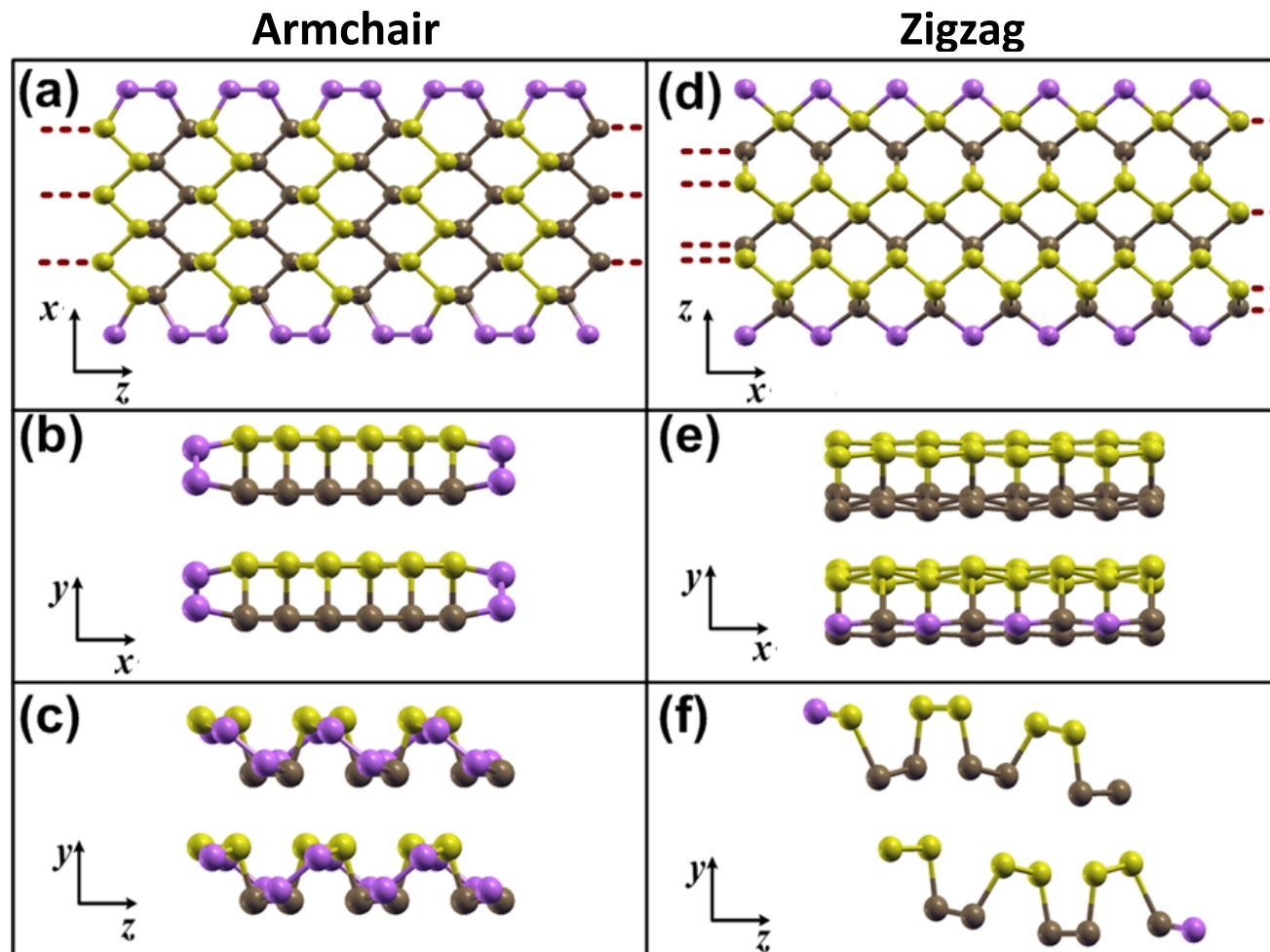




Modelling the edges with density functional theory (DFT)

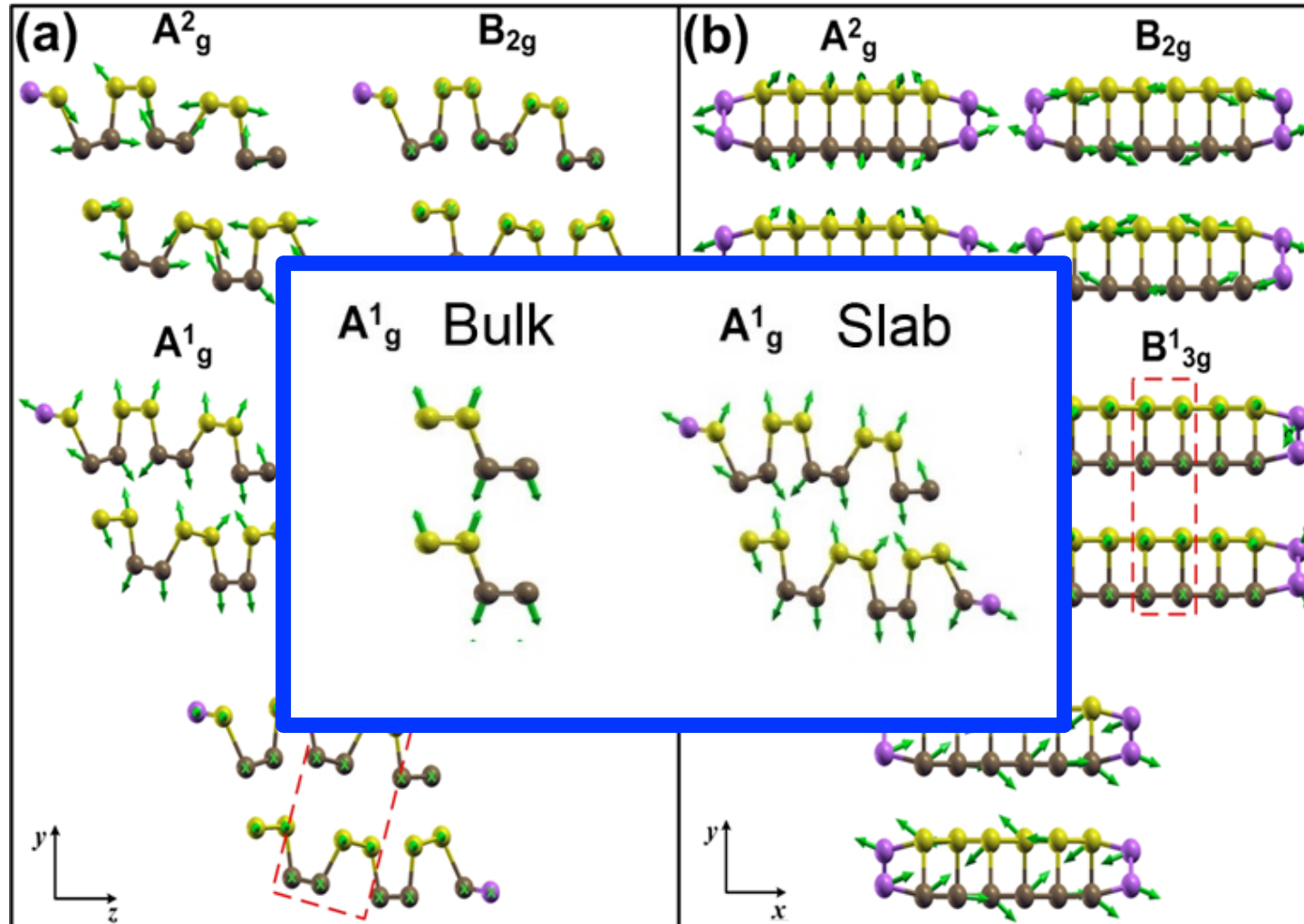


- BP slabs with zigzag and armchair surfaces simulated by DFT
- Atomic rearrangements





Origin of edge phonons



- Atomic rearrangements → deviations in atomic displacements at the edges

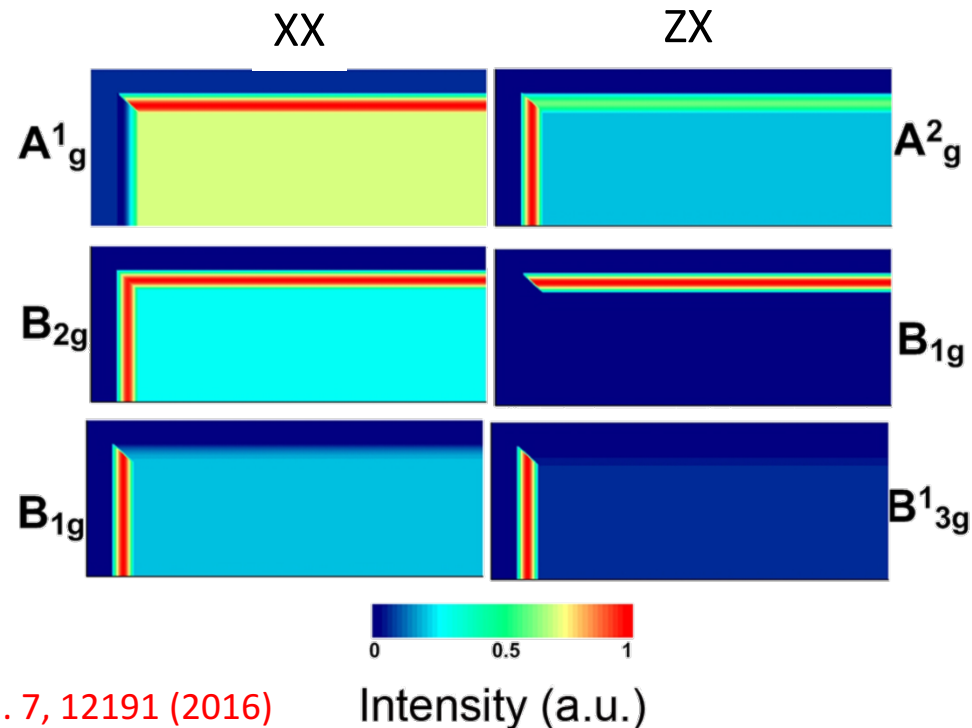


Raman tensors at BP edges calculated by DFPT

- Using density functional perturbation theory (DFPT), the dielectric tensor and the Raman intensities for the relaxed structures were evaluated for each mode

$$I^\nu \propto |\mathbf{e}_i \cdot A^\nu \cdot \mathbf{e}_s|^2 \frac{1}{\omega_\nu} (n_\nu + 1)$$

Polarized Raman edge effects reproduced:





Nonlinear optical frequency conversion in black phosphorus

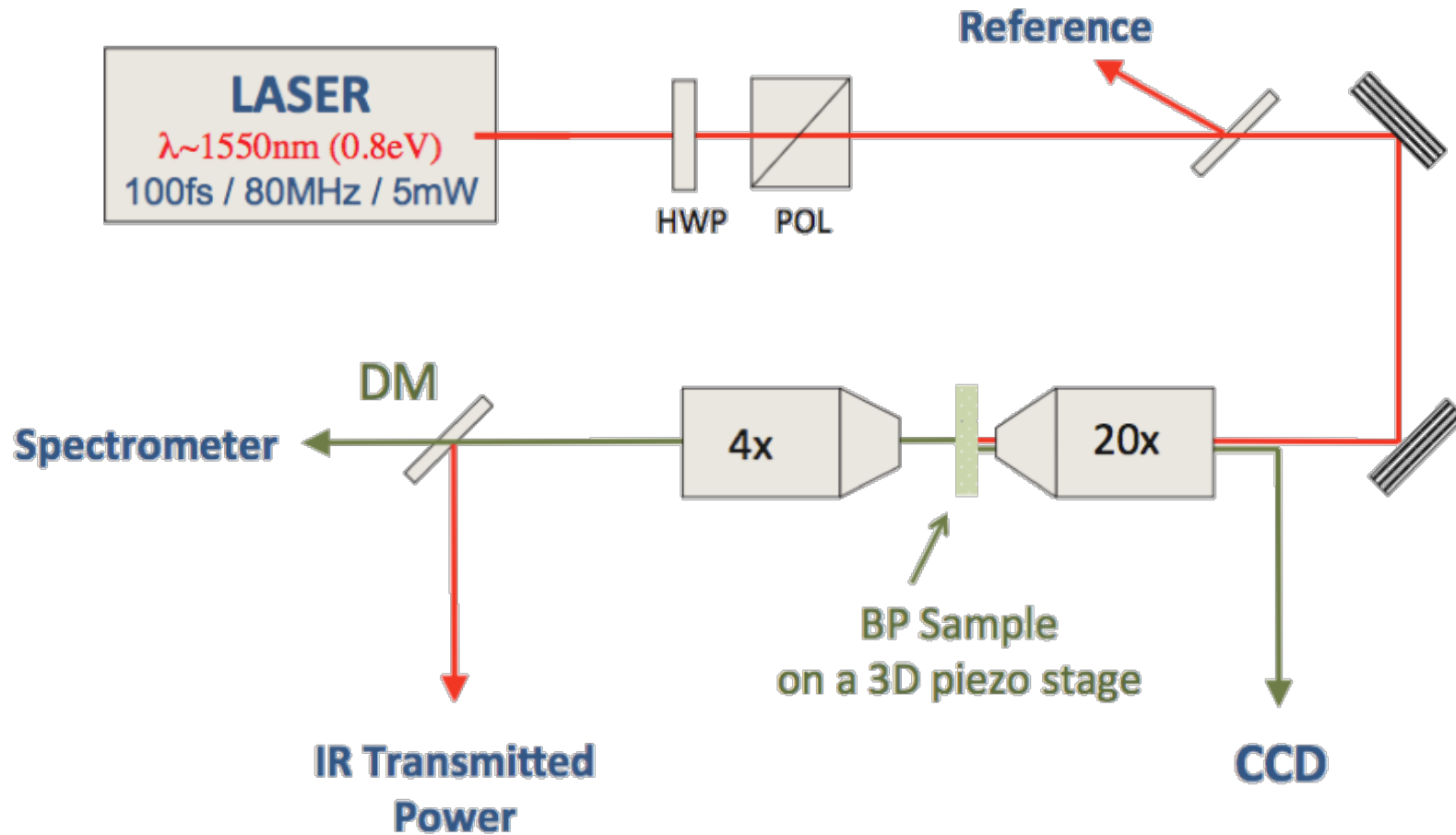




Sample preparation & experimental setup



- Experimental setup

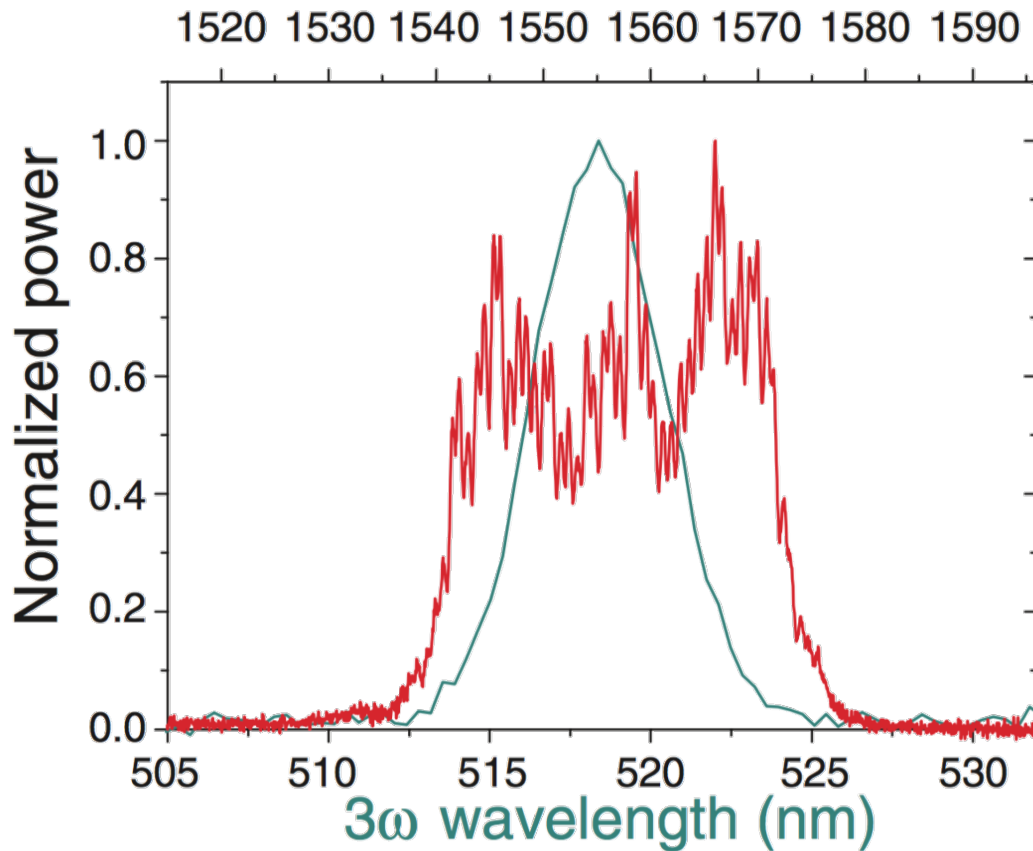




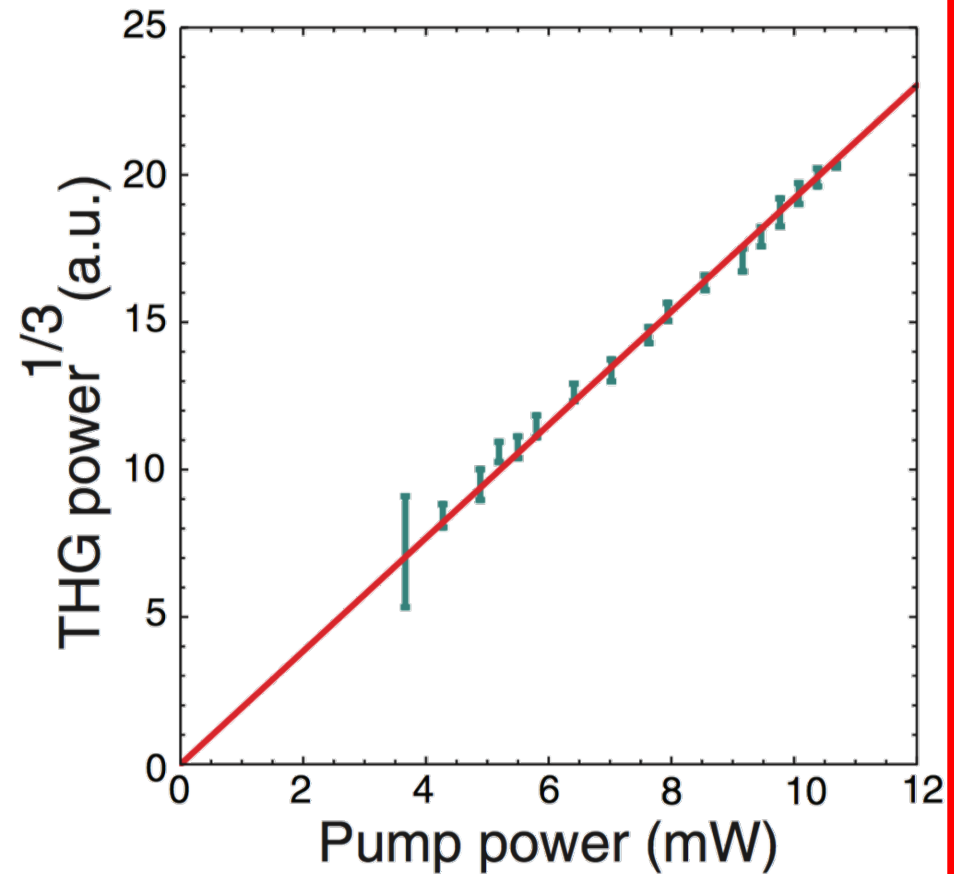
Nonlinear optical characterization - thick flake

Spectra

ω wavelength (nm)



Power dependence

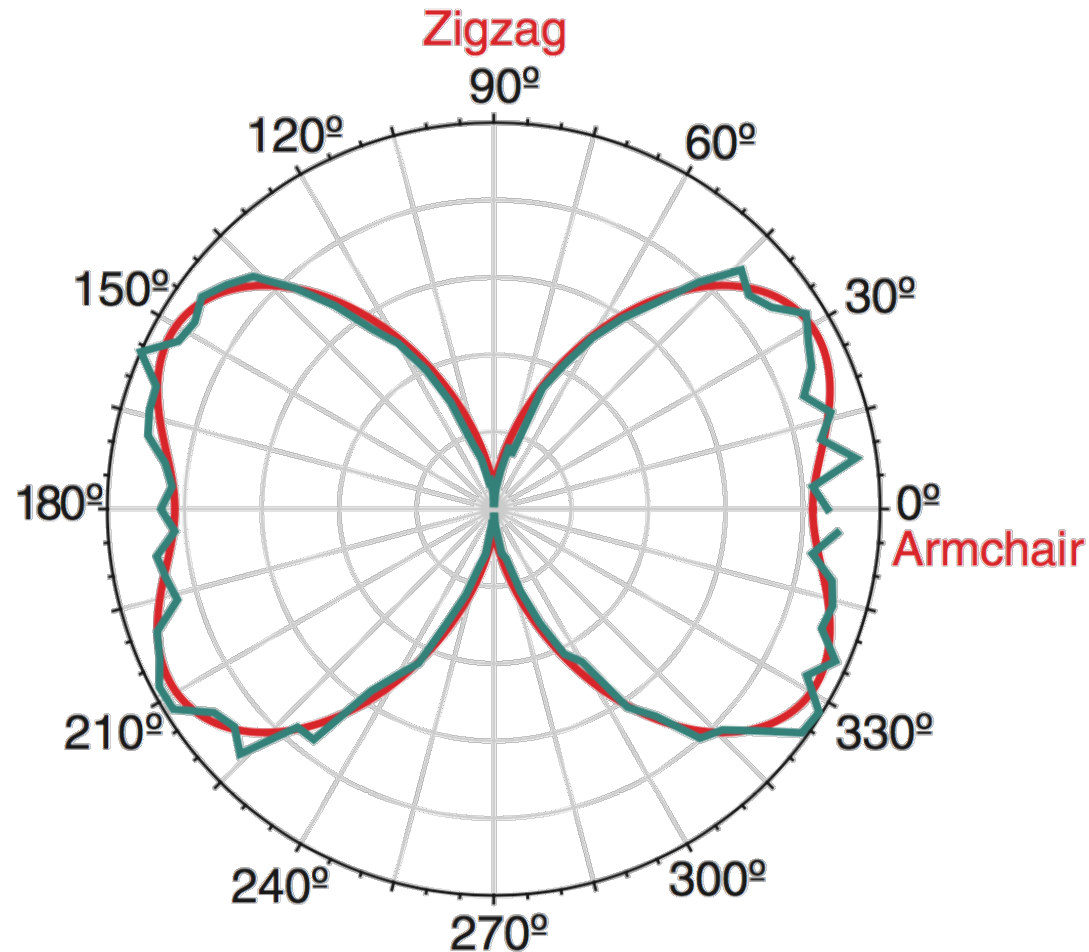


- Consistent with THG



Nonlinear optical characterization - thick flake

Polarization dependence

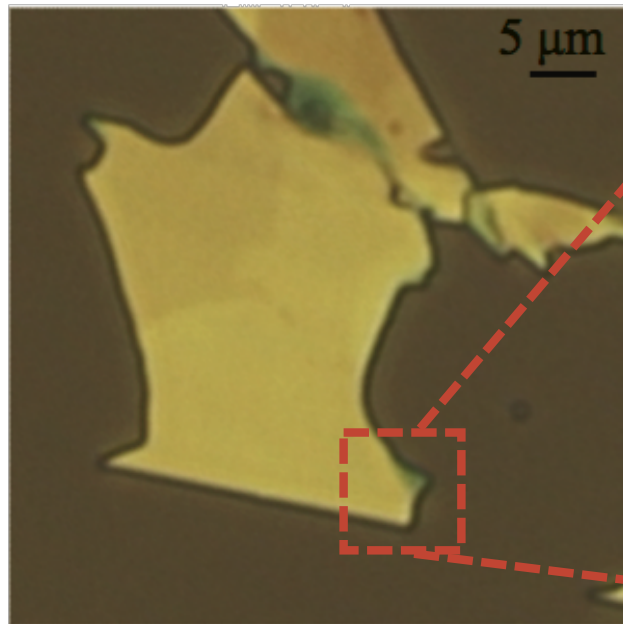


- Consistent with THG for point group D_{2h}

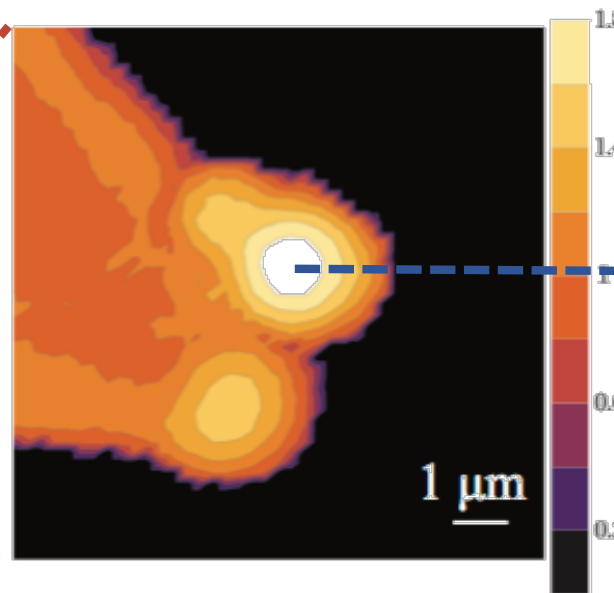


Nonlinear optical characterization - few-layer BP

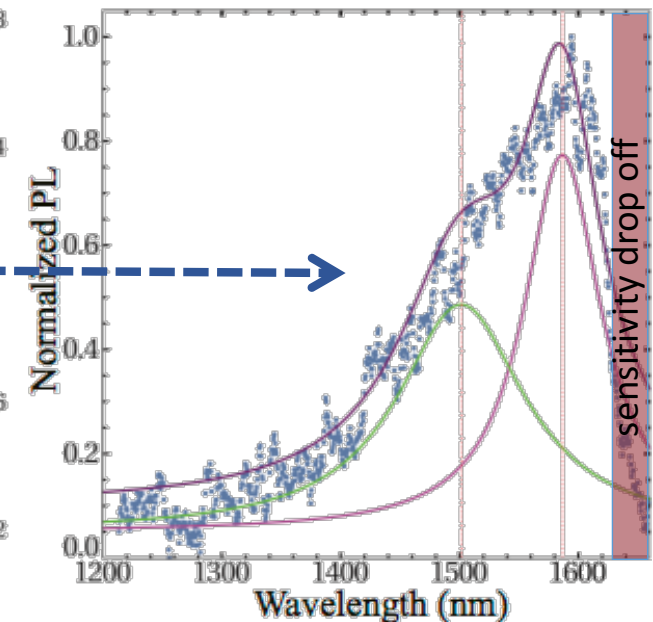
Optical image



THG map



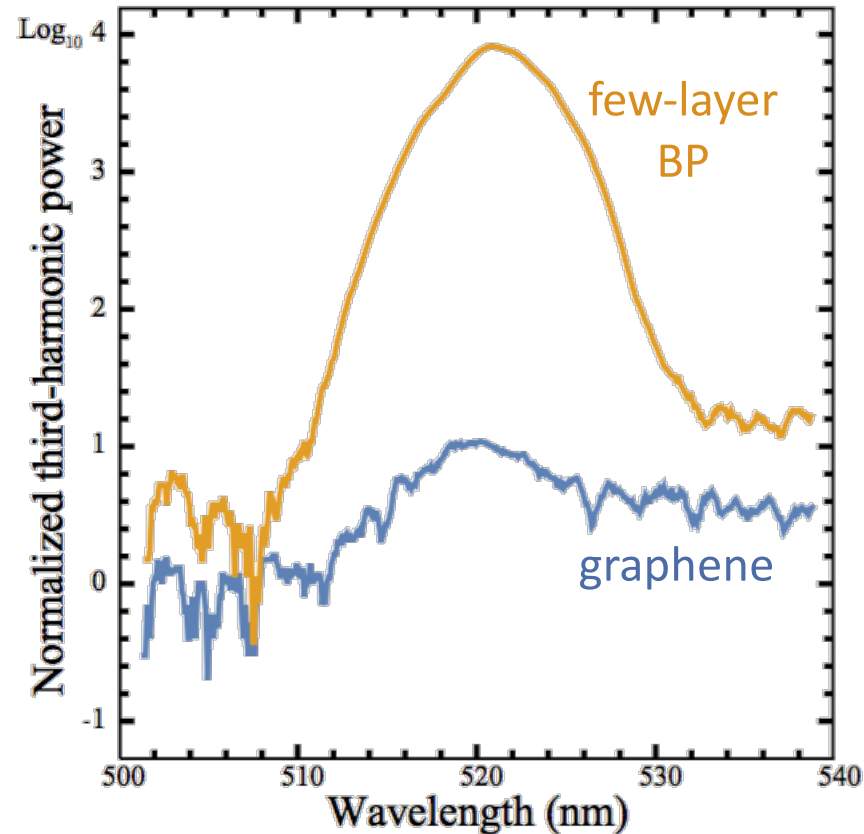
Luminescence spectrum



- Luminescence consistent with 4-5 BP layers
[J. Yang *et al.*, Light: Science & Applications 4, e312 (2015)]
- THG intensity an order of magnitude higher in the few layer region → resonant process?



Nonlinear susceptibility quantification



- Intensity with BP 3 orders of magnitude higher
- $\chi_S^{(3)}$ in BP $\sim 28\times$ higher than in graphene

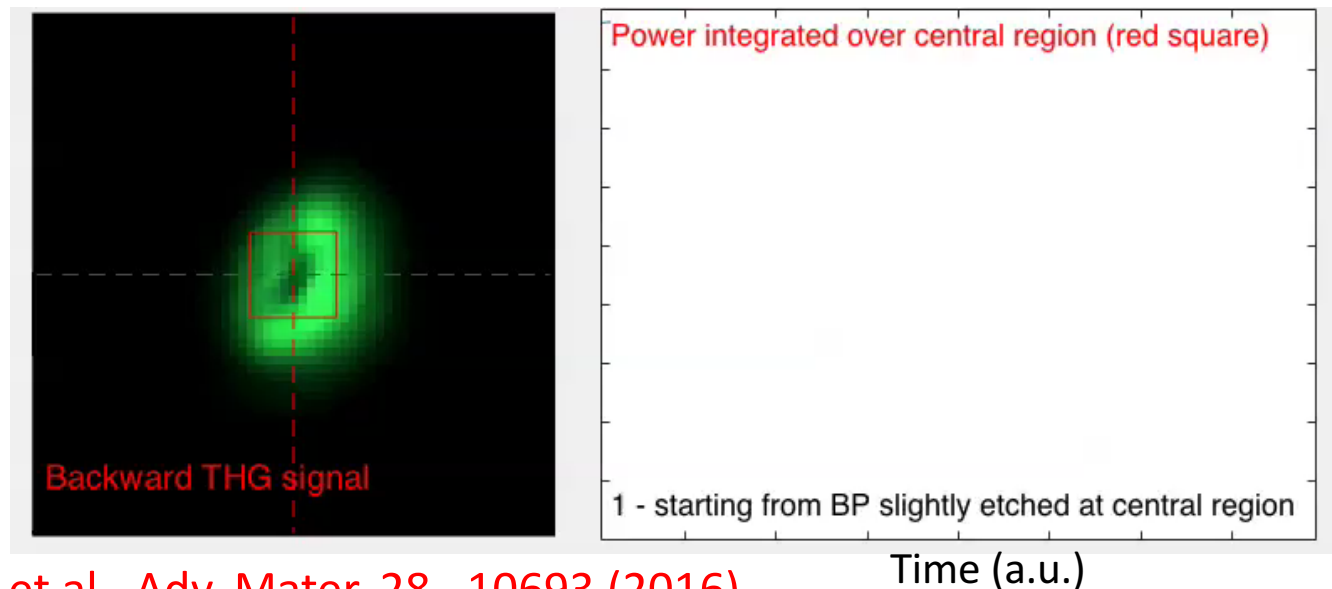
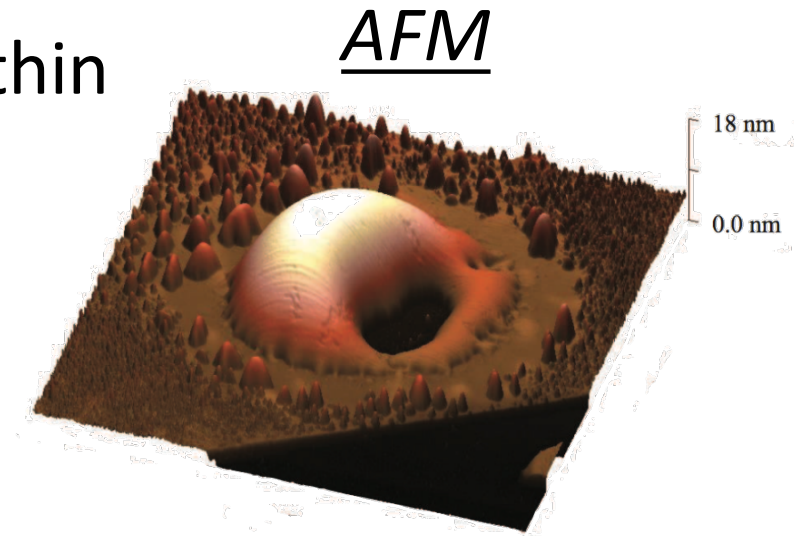


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Laser thinning and simultaneous THG monitoring



- Fluences $> 0.9 \text{ mJ/cm}^2$ found to thin BP flakes down
- THG can be simultaneously monitored:

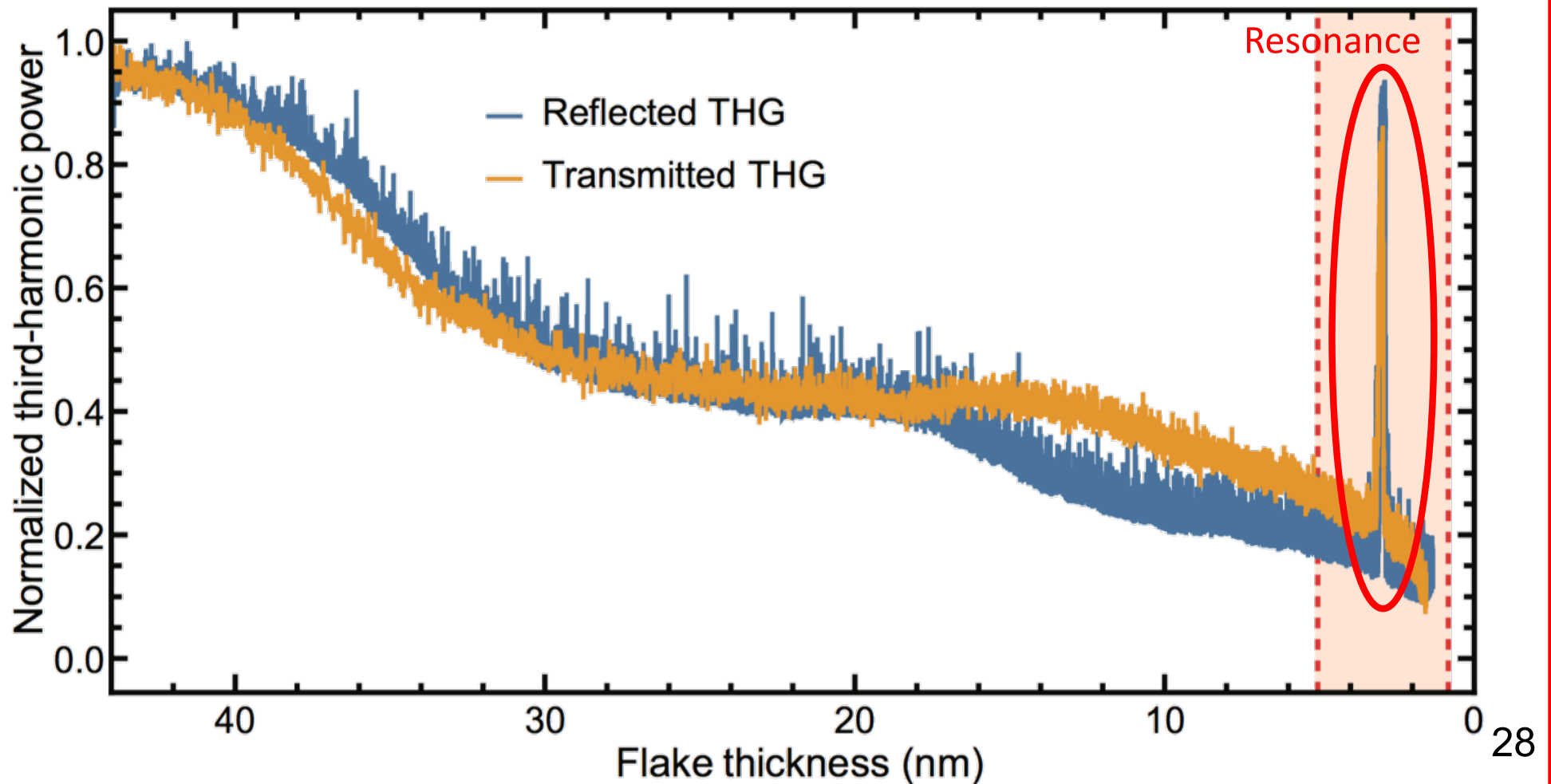




Laser thinning and simultaneous THG monitoring



- Average thinning rate calibrated from IR absorption





The origin of the enhanced nonlinearity



- Density functional theory suggests that the single particle picture is unable to reproduce resonance
- Preliminary exciton analysis, on the other hand, indicates a quasi-resonance for the few-layer thickness regime



Conclusions

- Black phosphorus presents a series of unusual properties
- Unusual polarized Raman scattering
 - Linear dichroism leads to complex Raman tensors
- Observation of edge phonons with anomalous symmetries
 - Local atomic rearrangement near the edges change atom displacements, generating new tensor elements
- Third-harmonic generation with drastic efficiency increase for few-layer thicknesses
 - (Quasi) resonance with excitonic states

Acknowledgments: collaborators



Henrique B. Ribeiro
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U F *m* G

Marcos A. Pimenta

unesp 

Cesar E. P. Villegas
Alexandre R. Rocha



Manuel J. L. F. Rodrigues
José Viana-Gomes
Antonio H. Castro Neto



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Acknowledgments

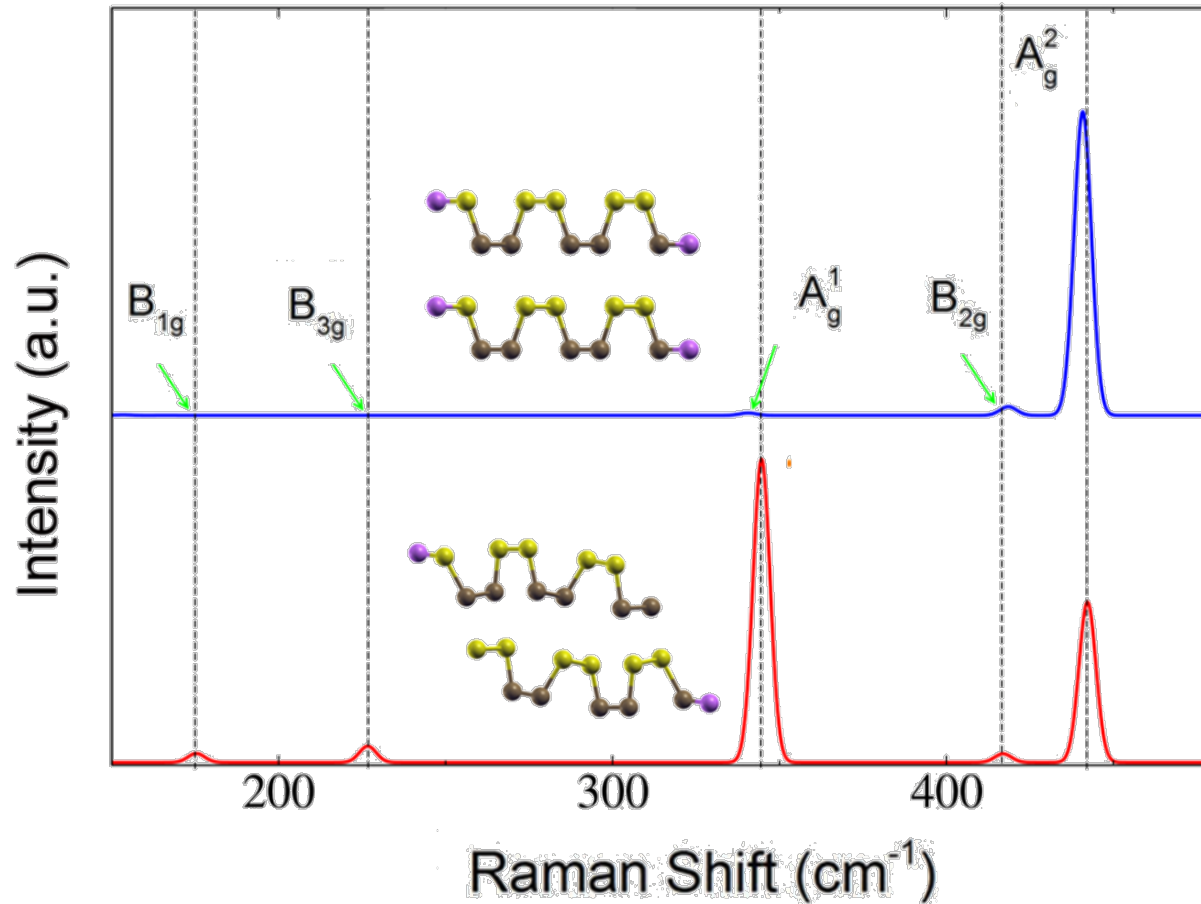


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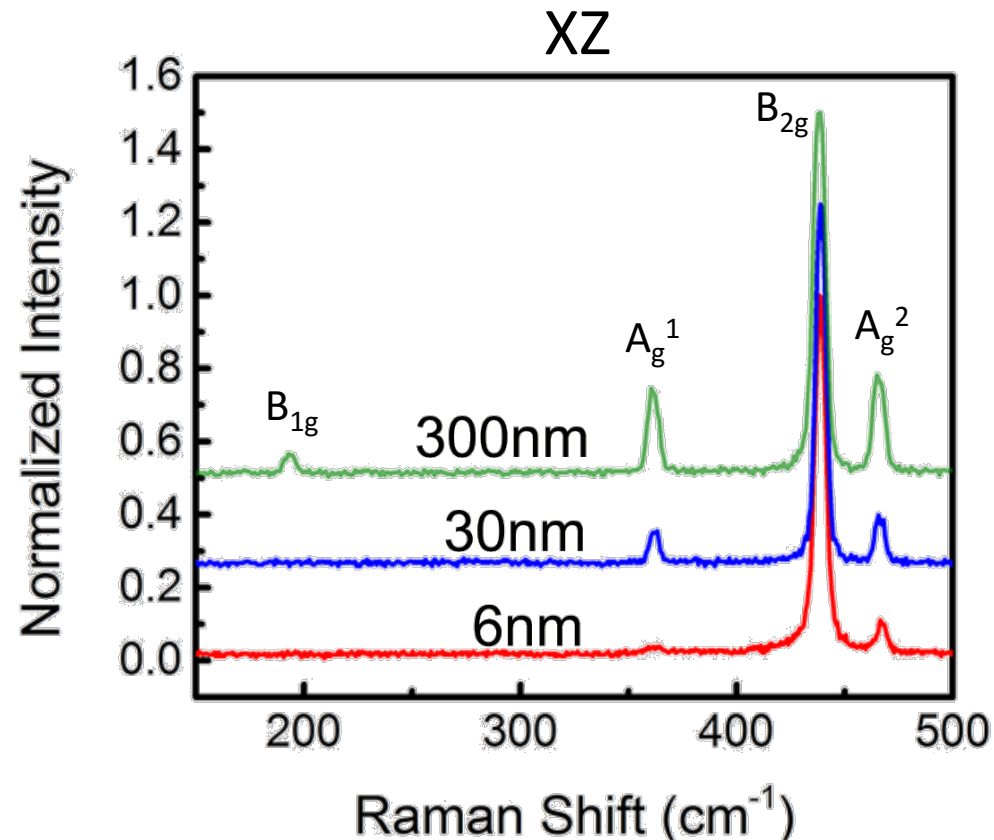
Truncated versus relaxed structure



- No edge effects observed in the truncated structure
- Edge phonons are, indeed, due to lattice relaxation



Edge phonons versus flake thickness



- Edge phonons still observed in the few-layer limit, even though with lower relative intensity